

SCHOTTKY BARRIER RECTIFIER

VOLTAGE RANGE: 30 - 100 V
CURRENT: 16 A

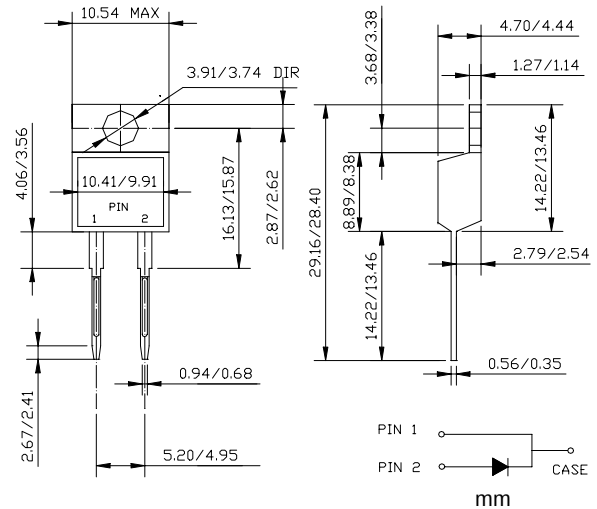
FEATURES

- ◇ High surge capacity.
- ◇ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- ◇ Metal silicon junction, majority carrier conduction.
- ◇ High current capacity, low forward voltage drop.
- ◇ Guard ring for over voltage protection.

MECHANICAL DATA

- ◇ Case: JEDEC TO-220AC, molded plastic body
- ◇ Terminals: Leads, solderable per MIL-STD-750, Method 2026
- ◇ Polarity: As marked
- ◇ Position: Any
- ◇ Weight: 0.064 ounces, 1.81 gram

TO-220AC



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

		MBR 1630	MBR 1635	MBR 1640	MBR 1645	MBR 1650	MBR 1660	MBR 1690	MBR 16100	UNITS
Maximum recurrent peak reverse voltage	V _{RRM}	30	35	40	45	50	60	90	100	V
Maximum RMS Voltage	V _{RMS}	21	25	28	32	35	42	63	70	V
Maximum DC blocking voltage	V _{DC}	30	35	40	45	50	60	90	100	V
Maximum average forw ard total device rectified current @T _C = 125°C	I _{F(AV)}	16								A
Peak forw ard surge current 8.3ms single half sine-w ave superimposed on rated load	I _{FSM}	150								A
Maximum forw ard (I _F =16A,T _C =25°C) voltage (Note 1) (I _F =16A,T _C =125°C)	V _F	0.63 0.57				0.75 0.65		0.85 -		V
Maximum reverse current @T _C =25°C at rated DC blocking voltage @T _C =125°C	I _R	0.2 40				1.0 50			m A	
Maximum thermal resistance (Note2)	R _{θJC}	1.5								
Operating junction temperature range	T _J	- 55 ---- + 150								°C
Storage temperature range	T _{STG}	- 55 ---- + 175								°C

NOTE: 1. Pulse test: 300μs pulse width, 1% duty cycle.

2. Thermal resistance from junction to case.

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FIG.1 – FORWARD CURRENT DERATING CURVE

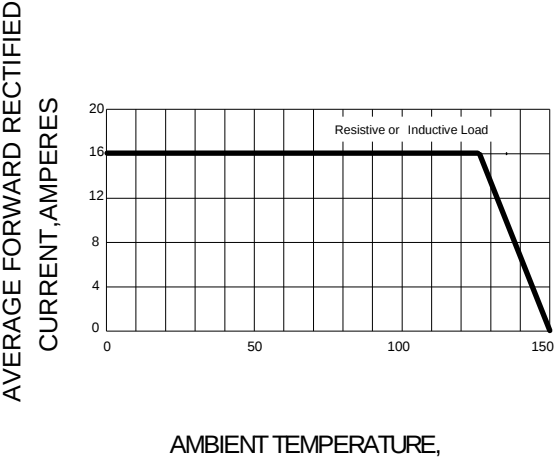


FIG.2 –MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

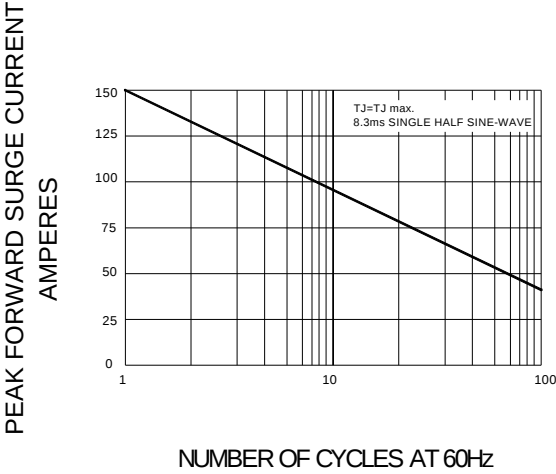


FIG.3 –TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

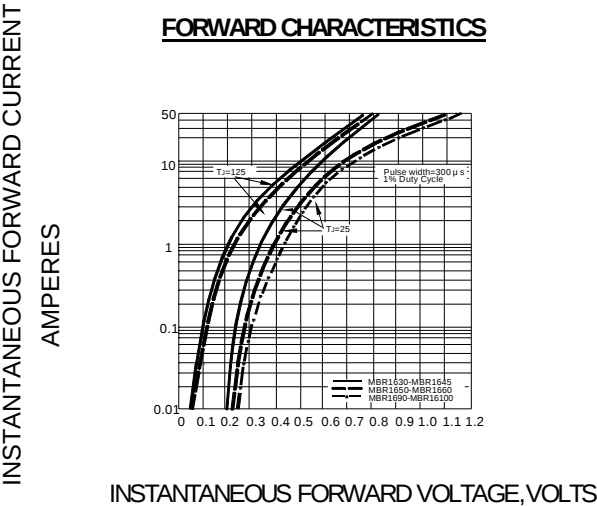


FIG.4-TYPICAL REVERSE CHARACTERISTICS

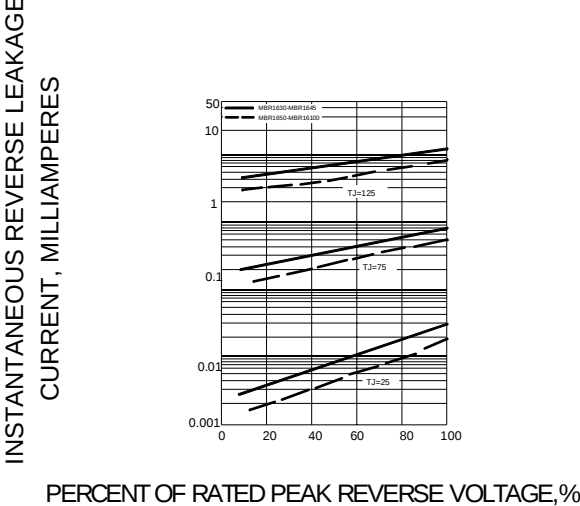


FIG.5-TYPICAL JUNCTION CAPACITANCE

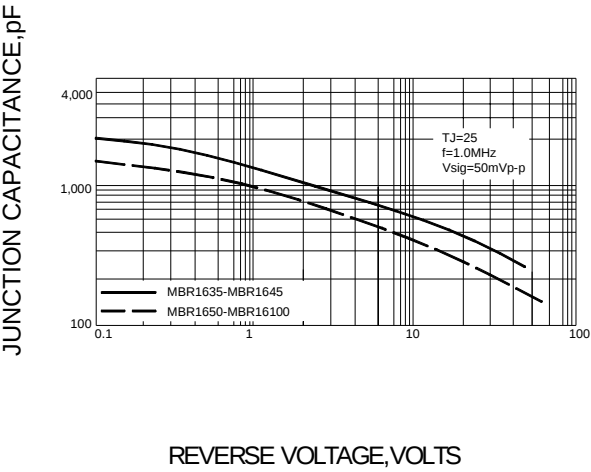


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

